

AMP1124 SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Class AB linear GaN design
 Instantaneous wide bandwidth
 Suitable for all modulations standards
 Small form factor & light weight
 Built-in protection circuits
 High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	0.7 - 4.2 GHz	
Power Output CW	200 Watt Typ	
Power Output @ P1dB GCP	80 Watt Min	100Watt Typ
Power Gain	53 dB Min	
Power Gain Flatness	4.0 dB p-p Max	Constant input power
Input / Output Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	>30 dBc Typ	43dBm/Tone, $\Delta = 1$ MHz
Harmonics	>20 dBc Typ	At rated Pout
Non Harmonics Spurious	>60 dBc	
Operating Voltage	32 VDC Nom	
Current Consumption	40 Amp Max	At rated Pout
Max Input Power	+8 dBm	Without damage
Load VSWR Protection	$\infty : 1$	

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +65 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	250 x 200 x 27mm	Excluding Connectors
Weight	2 Kg.	
RF Connectors In/Out	SMA / Type-N female	
DC Power / Interface Connector	Hybrid 9-Pin D-Sub	9W4
Cooling	External Heatsink	Forced air required

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D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	OPTION 101 - Forward power detect
2	VVA	OPTION 103 - Variable Voltage Attenuator
3	CURRENT SENSOR	$I_D @ 20\text{mV}/100\text{mA Typ}$
4	TEMP SENSOR	$V_T @ 10\text{mV}/^\circ\text{C} + 500\text{mV Typ}$
5	SHUTDOWN	TTL
A1, A2	VDD	32VDC
A3, A4	GND	Ground

OUTLINE DRAWING

